OP800SL Series, OP800WSL Series OP830SL Series, OP830WSL Series

Features:

- TO-18 hermetically sealed package
- Mechanically and spectrally matched to OP130 and OP230 LEDs
- TX and TXV process available (see Hi-Rel section)
- · Choice of narrow or wide receiving angle
- Variety of sensitivity ranges
- Enhanced temperature range



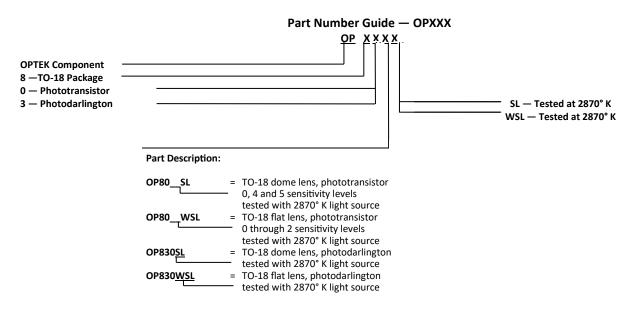
Each device in this series consists of a NPN silicon phototransistor mounted in a hermetically sealed TO-18 package that offers high power dissipation and superior hostile environment operation. The OP800SL, OP804SL, OP805SL and OP830SL devices have a narrow receiving angle that provides excellent on-axis coupling and a bonded base lead that enables conventional transistor biasing. The OP800WSL, OP801WSL, OP802WSL and OP830WSL all have a wide receiving angle that provides relatively even reception over a large area.

Devices are 100% production tested using an infrared light source for close correlation with OPTEK's GaAs and GaAlAs emitters. The OP800SL and devices are mechanically and spectrally matched to OP130 and OP230 series LEDs. The OP800WSL devices are mechanically and spectrally matched to OP130W and OP230W series devices.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

Applications:

- Space-limited applications
- Hostile environment applications
- · Applications requiring high power dissipation





General Note

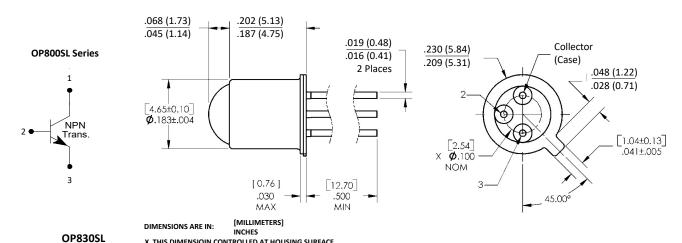
Electronics

"WSL"

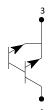
OP800SL Series, OP800WSL Series OP830SL Series, OP830WSL Series



OP800SL, OP830SL

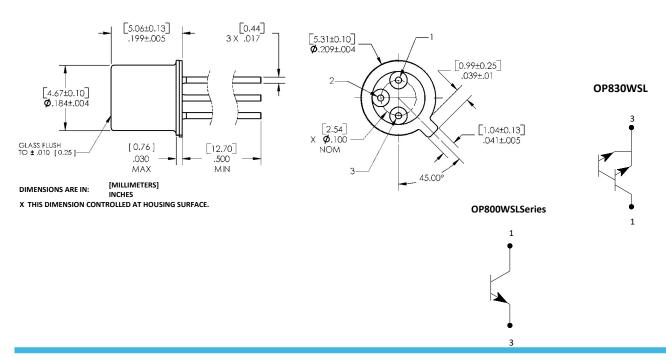


X THIS DIMENSIOIN CONTROLLED AT HOUSING SURFACE.



Pin #	OP80X	OP830		
1	Collector	Collector		
2	Base —			
3	Emitter Emitter			

OP800WSL, OP830WSL



OP800SL Series, OP800WSL Series OP830SL Series, OP830WSL Series



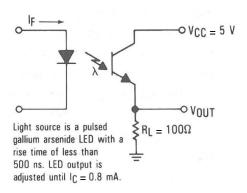
Electrical Specifications

Absolute Maximum Ratings (T _A = 25° C unless otherwise noted)	
Storage Temperature Range	-65°C to +150°C
Operating Temperature Range	-65°C to +125°C
Collector-Base Voltage (applies to OP800SL only - does not apply to OP800WSL)	30 V
Collector-Emitter Voltage OP800 (SL, WSL) OP830 (SL, WSL)	30 V 15 V
Emitter-Base Voltage (applies to OP800 (SL, WSL) only)	5 V
Emitter-Collector Voltage (applies to all OP800 and OP830 devices)	5 V
Continuous Collector Current	50 mA
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260° C ⁽¹⁾
Power Dissipation	250 mW ⁽²⁾

Notes

- 1. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum 20 grams force may be applied to the leads when soldering.
- 2. Derate linearly 2.5 mW/° C above 25° C.
- 3. Junction temperature maintained at 25° C.
- 4. Light source is an unfiltered tungsten bulb operating at CT = 2870 K.

Switching Time Test Circuit



OP800SL Series, OP800WSL Series OP830SL Series, OP830WSL Series



Electrical Specifications

YMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS	
I _{C(ON)} ⁽³⁾	On-State Collector Current OP800SL	0.5 7.0	-	- 22			
	OP804SL	15	-	-	mA	$V_{CE} = 5 \text{ V, } E_E = 5 \text{ mW/cm}^{(2)(3)(4)}$	
	OP805SL OP800WSL OP801WSL	0.3	-	3			
		0.5	-	2			
	OP802WSL	2.5	-	3			
	OP830SL	15	-	-		V _{CE} = 5 V, E _E = 0.5 mW/cm ⁽²⁾⁽³⁾⁽⁴⁾	
	OP830WSL	4	-	-		V(E = 3 V, EE = 0.3 mvV/cm	
	Collector Dark Current OP800 (SL, WSL)		_	100	nA	V _{CF} = 10 V, E _F = 0	
I _{CEO}	OP830 (SL, WSL)	-	-	1	IIA	$V_{CE} = 10 \text{ V}, E_E = 0$	
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	20			.,		
	OP800 (SL, WSL) OP830 (SL, WSL)	30 15	-	-	V	Ι _C = 100 μΑ	
V _{(BR)CBO}	Collector- Base Breakdown Voltage [applies to OP800SL only]	30	-	-	V	Ι _C = 100 μΑ	
V _{(BR)ECO}	Emitter-Collector Breakdown Voltage	5.0	-	-	V	Ι _Ε = 100 μΑ	
V _{(BR)EBO}	Emitter- Base Breakdown Voltage [applies to OP800SL only]	5.0	-	-	V	Ι _Ε = 100 μΑ	
V _{CE(SAT)} ⁽³⁾	Collector-Emitter Saturation Voltage OP800WSL	_	_	0.4		$I_C = 0.15 \text{ mA, } E_E = 0.5 \text{ mW/cm}^{2(4)}$	
	OP800SL	_	-	0.4	V	$I_C = 0.4 \text{ mA}, E_E = 5 \text{ mW/cm}^{2(4)}$	
	OP830SL	-	-	1.2		$I_C = 0.15 \text{ mA}, E_E = 0.5 \text{ mW/cm}^{2(4)}$	
	OP830WSL	-	-	1.2		$I_C = 1.0 \text{ mA, } E_E = 0.5 \text{ mW/cm}^{2(4)}$	
t _r	Rise Time	-	7	-	μs	V_{CC} = 5 V, I_{C} = 0.80 mA, R_{L} = 100 Ω (See Test Circuit)	
t _f	Fall Time	-	7	-	μs		

Notes:

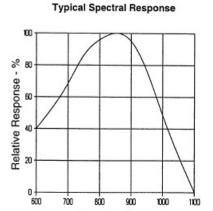
- 1. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum 20 grams force may be applied to the leads when soldering.
- 2. Derate linearly 2.5 mW/° C above 25° C.
- 3. Junction temperature maintained at 25° C.
- 4. Light source is an unfiltered tungsten bulb operating at CT = 2870 K or equivalent infrared source.

OP800SL Series, OP800WSL Series OP830SL Series, OP830WSL Series

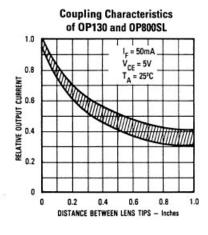


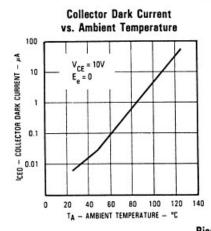
Performance

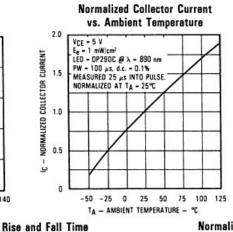
OP800SL Series

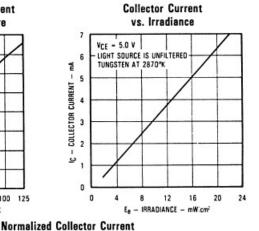


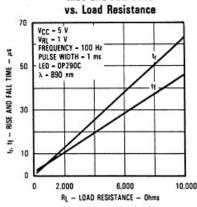
Wavelength - nm

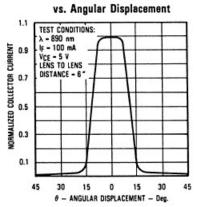










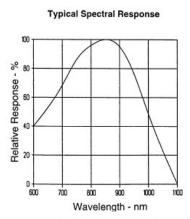


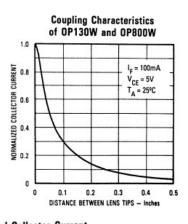
OP800SL Series, OP800WSL Series OP830SL Series, OP830WSL Series



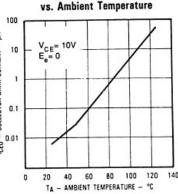
Performance

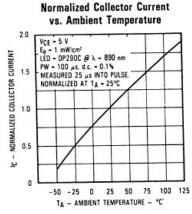
OP800WSL Series

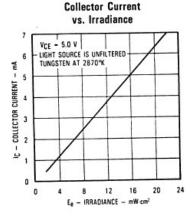




Collector Dark Current vs. Ambient Temperature 100 AH -10V 10 ICEO - COLLECTOR DARK CURRENT



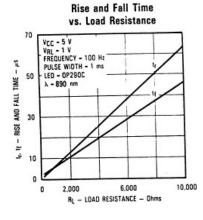


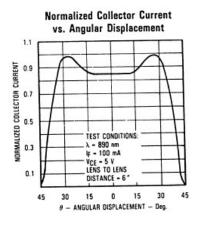


Rise and Fall Time vs. Load Resistance

Normalized Collector Current vs. Angular Displacement

Switching Time **Test Circuit**





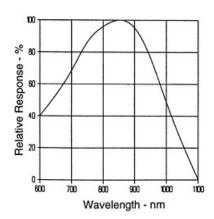
OP800SL Series, OP800WSL Series OP830SL Series, OP830WSL Series



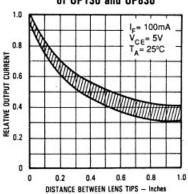
Performance

OP830SL Series

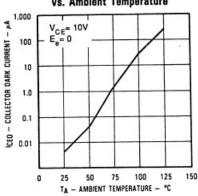
Typical Spectral Response



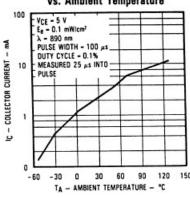
Coupling Characteristics of OP130 and OP830



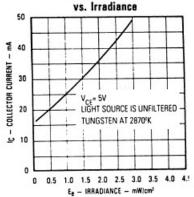
Collector Dark Current vs. Ambient Temperature



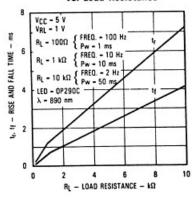
Collector Current vs. Ambient Temperature



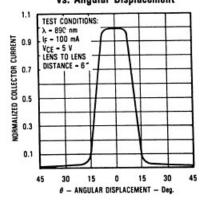
Collector Current vs. Irradiance



Rise and Fall Time vs. Load Resistance



Normalized Collector Current vs. Angular Displacement



OP800SL Series, OP800WSL Series OP830SL Series, OP830WSL Series



Performance

OP830WSL Series

